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High Power LED Series Chip on Board

LC008B



High efficacy COB LED package, well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability
- Completed 6,000 hours of LM-80 Testing
- ENEC certified: Integral LED Module

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination











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1. Characteristics

a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	°C	-
Storage Temperature	T_{stg}	-40 ~ +120	°C	-
LED Junction Temperature	Tj	140	°C	-
Case Temperature	Tc	105	°C	*Note
Forward Current	l _F	430	mA	-
Power Dissipation	P_D	15.8	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	_	±0.5	kV	_

b) Electro-optical Characteristics (I_F = 240 mA, T_a = 25 °C)

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V _F)	V	YH	33.5	36.5	39.5
		3	70	_	_
Out on December on Indian (D)		5	80	_	_
Color Rendering Index (Ra)	-	7	90	_	_
		8	95		
Thermal Resistance (junction to chip point)	°C/W		_	2.0	_
Beam Angle	0		_	115	_
Working Voltage for Insulation	V				50
Nominal Power	W			8.8	
Eye Protection		Risk 1	_		_

Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_i = T_c = T_a = 25$ °C)
- 2) Samsung maintains measurement tolerance of: forward voltage = ± 5 %, CRI = ± 1
- 3) Max Tc=105℃ (at max current) is for ENEC condition. Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.



c) Luminous Flux Characteristics (I_F = 240 mA, T_a = 25 °C)

CRI (R _a)	Nominal	Flux	Flux	Sorting ¹⁷ @1	$\Gamma_c = 25 ^{\circ}\text{C (Im)}$	Calculated Flux ²⁾	@ $T_c = 85 ^{\circ}\text{C}$ (Im
Min.	CCT (K)	Rank	Bin	Min.	Max.	Min.	Max.
	3000	MG	M1	1064	1209	958	1088
	3000	IVIG	M2	1209	1354	1088	1219
70	4000	MG	M1	1117	1270	1006	1143
70	4000	IVIG	M2	1270	1422	1143	1280
	5000	MG	M1	1128	1282	1015	1154
	3000	IVIG	M2	1282	1436	1154	1292
			K2	968	1041	881	947
		KE	K3	1041	1114	947	1014
	2700		K4	1114	1187	1014	1080
		KG	K3	1041	1114	947	1014
		NG	K4	1114	1187	1014	1080
			K2	1030	1108	937	1008
	3000	KE	K3	1108	1185	1008	1078
			K4	1185	1263	1078	1149
		VC	K3	1108	1185	1008	1078
		KG	K4	1185	1263	1078	1149
			K2	1061	1141	965	1038
		KE	K3	1141	1221	1038	1111
	3500		K4	1221	1300	1111	1183
		1/0	K3	1141	1221	1038	1111
00		KG	K4	1221	1300	1111	1183
80			K2	1092	1174	994	1068
		KE	K3	1174	1256	1068	1143
	4000		K4	1256	1338	1143	1218
		140	K3	1174	1256	1068	1143
		KG	K4	1256	1338	1143	1218
			K2	1102	1185	1003	1078
		KE	K3	1185	1268	1078	1154
	5000		K4	1268	1351	1154	1229
		1/0	K3	1185	1268	1078	1154
		KG	K4	1268	1351	1154	1229
			K2	1102	1185	1003	1078
		KE	K3	1185	1268	1078	1154
	5700		K4	1268	1351	1154	1229
			K3	1185	1268	1078	1154
		KG	K4	1268	1351	1154	1229



c) Luminous Flux Characteristics (I_F = 240 mA, T_a = 25 °C)

CRI (R _a)	Nominal	Flux Rank	Flux	Sorting ¹⁾ @ T	_c = 25 °C (lm)	Calculated Flux ²⁾	@ $T_c = 85 ^{\circ}\text{C (Im)}$						
Min.	CCT (K)		Bin	Min.	Max.	Min.	Max.						
			F2	859	933	781	849						
	2700	FG	F3	933	1008	849	917						
			F4	1008	1083	917	985						
			F2	876	952	797	867						
	3000	FG	F3	952	1029	867	936						
90			F4	1029	1105	936	1005						
90		FG	F2	903	981	821	893						
	3500		F3	981	1060	893	964						
			F4	1060	1138	964	1036						
		FG	F2	929	1010	845	919						
	4000		F3	1010	1090	919	992						
			F4	1090	1171	992	1066						
	2700	F0	F0.	F0	F0	EC	F0	F0	E1	756	840	688	764
	2700	EU	E2	840	924	764	841						
05	3000	FC	E1	779	866	709	788						
95	3000	EC	E2	866	953	788	867						
	2500	EC	E1	803	892	731	812						
	3500	EU	E2	892	981	812	893						

Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_i = T_c = T_a = 25$ °C)
- 2) Calculated flux values are for reference only
- 3) Samsung maintains measurement tolerance of: luminous flux = ± 7 %, CRI = ± 1



2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	н	C	w	-1	н	D	N	9	4	5	Y	н	R	т	K	F

Digit	PKG Information	Code				Specificat	tion
1 2 3	Samsung Package High Power	SPH					
4 5	0.1	ww	Warm White	(T/U/	V/W Rank	(S)	
4 5	Color	cw	Cool White	(Q/R	Ranks)		
6	Product Version	1					
7 8	Form Factor	HD	СОВ				
9	Lens Type	N	No lens				
10	Internal Code	9	LC008				
11	Chip Type	4					
		3	Min. 70				
12	CRI & Sorting Temperature	5	Min. 80 2	.5 °C			
	Orti d Corting Temperature	7	Min. 90				
		8	Min 95				
13 14	Forward Voltage (V)	YH	33.5~39.5				
		W	2700 K		WA,WB	(MacAdam Ellipse)	
		V	3000 K		VA, VB	(MacAdam Ellipse)	VW, VX, VY, VZ (ANSI bin)
15	CCT (K)	U		Bin	UA, UB	(MacAdam Ellipse)	
	001 (14)	Т	4000 K	Code:	TA, TB	(MacAdam Ellipse)	TW, TX, TY, TZ (ANSI bin)
		R	5000 K		RA	(MacAdam Ellipse)	RW, RX, RY, RZ (ANSI bin)
		Q	5700 K				QW, QX, QY, QZ (ANSI bin)
		2	MacAdam 2-	-step			
16	MacAdam / ANSI	3	MacAdam 3-	-step			
		Т	ANSI bin				
		MG			M1, M2	(70 CRI)	
		KE		D:		4 (80 CRI)	
17 18	Luminous Flux	KG		Bin Code:	K3, K4 (80 CRI)	
		FG			F2, F3, F4	4 (90 CRI)	
		EC			E1, E2 (9	5 CRI)	



a) Binning Structure (I_F = 240 mA, T_a = 25 °C)

CRI (R₃) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ _v , lm)				
	0000	ODLINAVAGA I DNIO 40VI IV TAMO	VIII	\ <i>T</i>	VW, VX	MO	M1	1064 ~ 1209				
	3000	SPHWW1HDN943YHVTMG	ΥH	VT	VY, VZ	MG	M2	1209 ~ 1354				
70	4000		N/11		TW, TX	MO	M1	1117 ~ 1270				
70	4000	SPHWW1HDN943YHTTMG	ΥH	TT	TY, TZ	MG	M2	1270 ~ 1422				
	5000	CDLICWALIDMO 40VI IDTMC	VII	DT	RW, RX	MO	M1	1128 ~ 1282				
	5000	SPHCW1HDN943YHRTMG	ΥH	RT	RY, RZ	MG	M2	1282 ~ 1436				
							K2	968 ~ 1041				
		SPHWW1HDN945YHW2KE	YH	W2	WB	KE	K3	1041 ~ 1114				
							K4	1114 ~ 1187				
							K2	968 ~ 1041				
	2700	SPHWW1HDN945YHW3KE	YH	W3	WA, WB	KE	K3	1041 ~ 1114				
	2700						K4	1114 ~ 1187				
		CDLIMMAT IDMOASVI IMOKO	VII	14/0	WD	1/0	K3	1041 ~ 1114				
		SPHWW1HDN945YHW2KG	ΥH	W2	WB	KG	K4	1114 ~ 1187				
		CDLIMMALIDMOAEVI IMOKO	VII	14/0	\A/A \A/D	1/0	K3	1041 ~ 1114				
		SPHWW1HDN945YHW3KG	ΥH	W3	WA, WB	KG	K4	1114 ~ 1187				
							K2	1030 ~ 1108				
					SPHWW1HDN945YHV2KE	YH	V2	VB	KE	K3	1108 ~ 1185	
								K4	1185 ~ 1263			
												K2
00		SPHWW1HDN945YHV3KE	YH	V3	VA, VB	KE	K3	1108 ~ 1185				
80	3000						K4	1185 ~ 1263				
			N/11		\/D	1/0	K3	1108 ~ 1185				
		SPHWW1HDN945YHV2KG	ΥH	V2	VB	KG	K4	1185 ~ 1263				
			N/11	140	\/A \/D	1/0	K3	1108 ~ 1185				
		SPHWW1HDN945YHV3KG	ΥH	V3	VA, VB	KG	K4	1185 ~ 1263				
							K2	1061 ~ 1141				
		SPHWW1HDN945YHU2KE	YH	U2	UB	KE	K3	1141 ~ 1221				
							K4	1221 ~ 1300				
							K2	1061 ~ 1141				
	0500	SPHWW1HDN945YHU3KE	YH	U3	UA, UB	KE	K3	1141 ~ 1221				
	3500						K4	1221 ~ 1300				
		CDL/M/M/TDMO4E//THOK/O	VII	110	LID	KC.	K3	1141 ~ 1221				
		SPHWW1HDN945YHU2KG	YH	U2	UB	KG	K4	1221 ~ 1300				
		CDLIMMALIDMOAEVI II IOKO	VII	110	114 115	KO.	K3	1141 ~ 1221				
		SPHWW1HDN945YHU3KG	ΥH	U3	UA, UB	KG	K4	1221 ~ 1300				



a) Binning Structure (I_F = 240 mA, T_a = 25 °C)

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ _v , lm)			
							K2	1092 ~ 1174			
		SPHWW1HDN945YHT2KE	ΥH	T2	TB	KE	K3	1174 ~ 1256			
							K4	1256 ~ 1338			
							K2	1092 ~ 1174			
	4000	SPHWW1HDN945YHT3KE	ΥH	Т3	TA, TB	KE	K3	1174 ~ 1256			
	4000						K4	1256 ~ 1338			
		SPHWW1HDN945YHT2KG	ΥH	T2	ТВ	KG	K3	1174 ~ 1256			
		SPHWWINDIN943THIZNG	IП	12	I D	NG	K4	1256 ~ 1338			
		SPHWW1HDN945YHT3KG	ΥH	Т3	TA, TB	KG	K3	1174 ~ 1256			
		SPHWWINDIN943THISKG	1 17	13	1A, 1D	NG	K4	1256 ~ 1338			
	-						K2	1102 ~ 1185			
		SPHCW1HDN945YHR3KE	ΥH	R3	RA	KE	K3	1185 ~ 1268			
80							K4	1268 ~ 1351			
										K2	1102 ~ 1185
		SPHCW1HDN945YHRTKE	ΥH	RT	RW, RX, RY, RZ	KE	K3	1185 ~ 1268			
	5000						K4	1268 ~ 1351			
	**		ΥH	R3	RA	1/0	K3	1185 ~ 1268			
		SPHWW1HDN945YHR3KG	ΥH	НЗ	KA	KG	K4	1268 ~ 1351			
			VIII	DT	RW, RX,	1/0	K3	1185 ~ 1268			
		SPHWW1HDN945YHRTKG	ΥH	RT	RY, RZ	KG	K4	1268 ~ 1351			
							K2	1102 ~ 1185			
		SPHCW1HDN945YHQTKE	YH	QT	QW, QX, QY, QZ	KE	K3	1185 ~ 1268			
	5700						K4	1268 ~ 1351			
		CDI IMAMALI DNIQAEVI IOTICO	VII	ОТ	QW, QX,	VC.	K3	1185 ~ 1268			
		SPHWW1HDN945YHQTKG	YH	QT	QY, QZ	KG ·	K4	1268 ~ 1351			

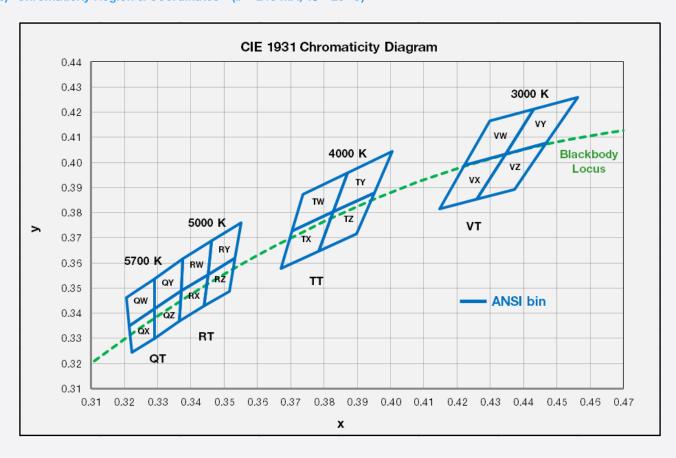


a) Binning Structure (I_F = 240 mA, T_a = 25 °C)

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ _v , lm)			
							F2	859 ~ 933			
		SPHWW1HDN947YHW2FG	ΥH	W2	WB	FG	F3	933 ~ 1008			
	2700						F4	1008 ~ 1083			
	2700						F2	859 ~ 933			
		SPHWW1HDN947YHW3FG	ΥH	W3	WA, WB	FG	F3	933 ~ 1008			
							F4	1008 ~ 1083			
							F2	876 ~ 952			
		SPHWW1HDN947YHV2FG	ΥH	V2	VB	FG	F3	952 ~ 1029			
	0000						F4	1029 ~ 1105			
	3000						F2	876 ~ 952			
		SPHWW1HDN947YHV3FG	YH	V3	VA, VB	FG	F3	952 ~ 1029			
00							F4	1029 ~ 1105			
90	3500						F2	903 ~ 981			
		SPHWW1HDN947YHU2FG	ΥH	U2	UB	FG	F3	981 ~ 1060			
							F4	1060 ~ 1138			
							F2	903 ~ 981			
		SPHWW1HDN947YHU3FG	ΥH	U3	UA, UB	FG	F3	981 ~ 1060			
							F4	1060 ~ 1138			
							F2	929 ~ 1010			
				SPH	SPHWW1HDN947YHT2FG	ΥH	T2	ТВ	FG	F3	1010 ~ 1090
							F4	1090 ~ 1171			
				Т3			F2	929 ~ 1010			
		SPHWW1HDN947YHT3FG	ΥH		TA, TB	FG	F3	1010 ~ 1090			
							F4	1090 ~ 1171			
							E1	756 ~ 840			
		SPHWW1HDN948YHW2EC	ΥH	W2	WB	EC	E2	840 ~ 924			
	2700						E1	756 ~ 840			
		SPHWW1HDN948YHW3EC	ΥH	W3	WA,WB	EC	E2	840 ~ 924			
							E1	779 ~ 866			
		SPHWW1HDN948YHV2EC	ΥH	V2	VB	EC	E2	866 ~ 953			
95	3000						E1	779 ~ 866			
		SPHWW1HDN948YHV3EC	ΥH	V3	VA,VB	EC	E2	866 ~ 953			
							E1	803 ~ 892			
		SPHWW1HDN948YHU2EC	ΥH	U2	UB	EC	E2	892 ~ 981			
	3500						E1	803 ~ 892			
		SPHWW1HDN948YHU3EC	YH	U3	UA,UB	EC	E2	892 ~ 981			



b) Chromaticity Region & Coordinates (I_F = 240 mA, T_a = 25 °C)

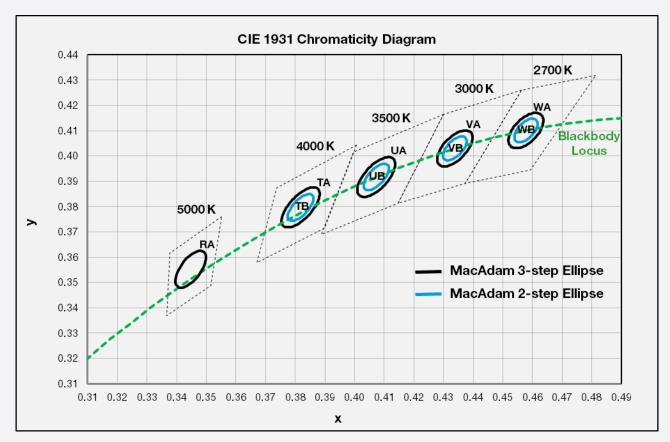


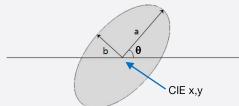
Region	CIE x	CIE y	Region	CIE x	CIE y					
	V rank (3000 K)									
	0.4223	0.399		0.4345	0.4033					
VW	0.4345	0.4033	VY	0.4468	0.4077					
VVV	0.4431	0.4213	Vĭ	0.4562	0.4260					
	0.4299	0.4165		0.4431	0.4213					
	0.4223	0.399		0.4260	0.3854					
VX	0.4147	0.3814	V7	0.4373	0.3893					
VX	0.4260	0.3854	VZ.	0.4468	0.4077					
	0.4345	0.4033		0.4345	0.4033					
		R rank	(5000 K)							
	0.3376	0.3616		0.3463	0.3687					
DIM	0.3463	0.3687	DV.	0.3551	0.3760					
RW	0.3451	0.3554	RY	0.3533	0.3620					
	0.3371	0.3490		0.3451	0.3554					
	0.3371	0.3490		0.3451	0.3554					
DV	0.3451	0.3554	DZ	0.3533	0.3620					
RX	0.3440	0.3428	RZ	0.3515	0.3487					
	0.3366	0.3369		0.3440	0.3428					

Region	CIE x	CIE y	Region	CIE x	CIE y
		T rank	(4000 K)		
	0.3736	0.3874		0.3871	0.3959
TW	0.3871	0.3959	TY	0.4006	0.4044
IVV	0.3828	0.3803	11	0.3952	0.388
	0.3703	0.3726		0.3828	0.3803
	0.3703	0.3726		0.3828	0.3803
TX	0.3828	0.3803	T-7	0.3952	0.388
1.	0.3784	0.3647	TZ	0.3898	0.3716
	0.367	0.3578		0.3784	0.3647
		Q rank	(5700 K)		
	0.3207	0.3462		0.3290	0.3538
014/	0.3290	0.3538	QY	0.3376	0.3616
QW	0.3290	0.3417	QT	0.3371	0.3490
	0.3215	0.3350		0.3290	0.3417
	0.3215	0.3350		0.3290	0.3417
QX	0.3290	0.3417	QZ	0.3371	0.3490
QX	0.3290	0.3300	QZ.	0.3366	0.3369
	0.3222	0.3243		0.3290	0.3300



b) Chromaticity Region & Coordinates (I_F = 240 mA, T_a = 25 °C)





MacAdam Ellipse (WA, WB)						
Step CIE x CIE y θ a						
2-step	0.4578	0.4101	53.70	0.0054	0.0028	
3-step	0.4578	0.4101	53.70	0.0081	0.0042	

MacAdam Ellipse (UA, UB)						
Step CIE x CIE y θ a						
2-step	0.4073	0.3917	54.00	0.0062	0.0028	
3-step	0.4073	0.3917	54.00	0.0093	0.0041	

MacAdam Ellipse (RA)						
Step CIE x CIE y θ a b						
3-step 0.3447 0.3553 59.62 0.0082 0.000						

MacAdam Ellipse (VA, VB)							
Step		b					
2-step	0.4338	0.403	53.22	0.0056	0.0027		
3-step	0.4338	0.4030	53.22	0.0083	0.0041		

MacAdam Ellipse (TA, TB)							
Step	CIE x CIE y θ a b						
2-step	0.3818	0.3797	53.72	0.0063	0.0027		
3-step	0.3818	0.3797	53.72	0.0094	0.0040		

Note:

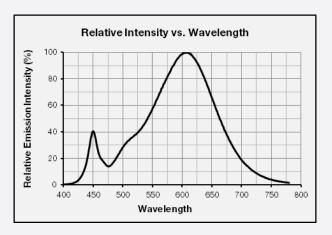
Samsung maintains measurement tolerance of: Cx, $Cy = \pm 0.005$



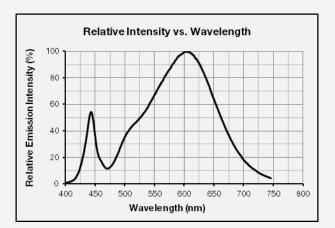
3. Typical Characteristics Graphs

a) Spectrum Distribution (I_F = 240 mA, T_a = 25 °C)

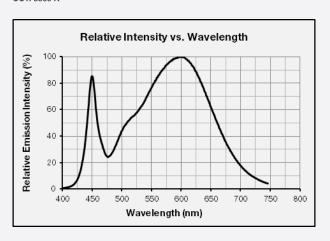
CCT: 2700 K



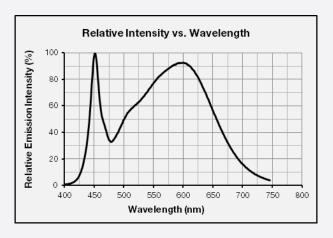
CCT: 3000 K



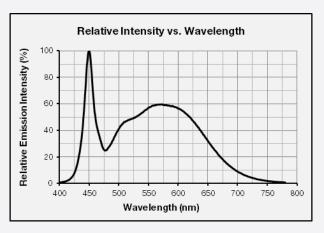
CCT: 3500 K



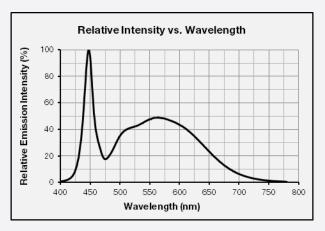
CCT: 4000 K



CCT: 5000 K

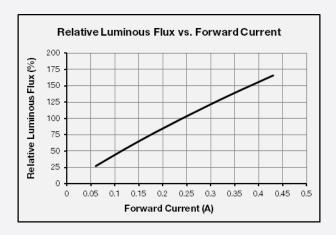


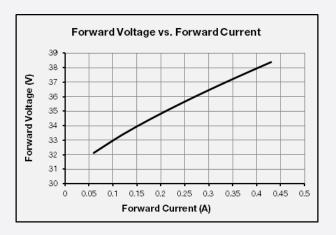
CCT: 5700 K



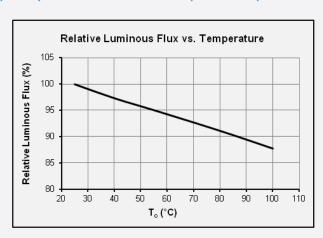


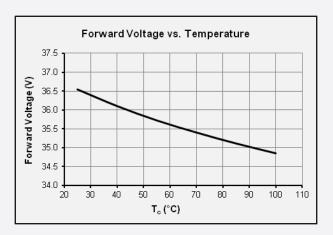
b) Forward Current Characteristics (T_a = 25 °C)





c) Temperature Characteristics (I_F = 240 mA)

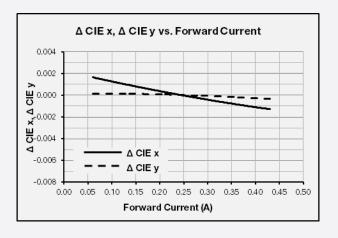


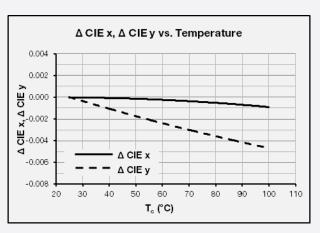


d) Color Shift Characteristics



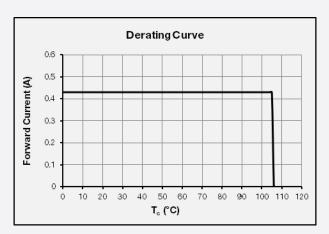
 $I_F = 240 \text{ mA}$



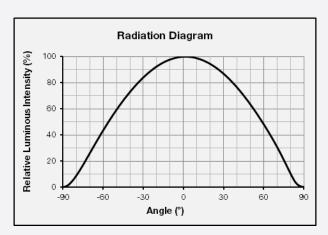




e) Derating Curve

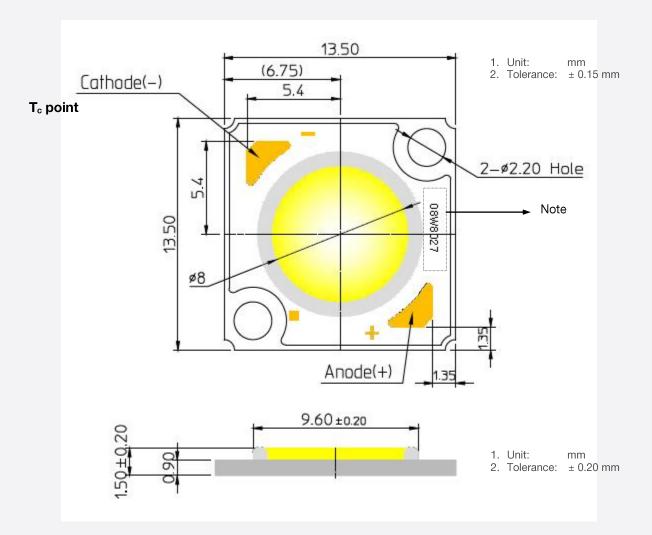


f) Beam Angle Characteristics (I_F = 240 mA, T_a = 25 °C)





4. Outline Drawing & Dimension



ltem	Dimension	Tolerance	Unit
Length	13.50	±0.15	mm
Width	13.50	±0.15	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	8	±0.15	mm
Screw Hole Size	2.2	±0.15	mm

Note: Denoted product information above is only an example

(08W8027:8.6W, CRI80+, 2700K)



5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle
Room Temperature Life Test	25 °C, I _F = max	1000 h
High Temperature Humidity Life Test	60 °C, 90 % RH, DC Derating, I _F = max	1000 h
High Temperature Life Test	105 °C, DC Derating, I _F = max	1000 h
Low Temperature Life Test	-40 °C, DC 430 mA	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Thermal Shock	-45 °C / 15 min ↔ 125 °C / 15 min temperature change in 5 min	200 cycles
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 100 min transfer power on/off each 5 min, DC 240 mA	100 cycles
ESD (HBM)	R_1 : 10 $M\Omega$ R_2 : 1.5 $k\Omega$ C : 100 pF V : ± 2 kV	5 times
ESD (MM)	R_{1} : $10M\Omega$ R_{2} : $0k\Omega$ C : $200pF$ V : $\pm 0.5kV$	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Salt Spray Test	35 ℃, 5 % salt water 8 h spray, 16 h dwell	2 cycles

b) Criteria for Judging the Damage

ltem	Symbol	Test Condition	Test Condition Limit	nit
item	Зуптоог	(T _c = 25 °C)	Min.	Max.
Forward Voltage	V_{F}	$I_F = 240 \text{ mA}$	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	$\Phi_{\scriptscriptstyle V}$	I _F = 240 mA	L.S.L * 0.7	U.S.L * 1.3

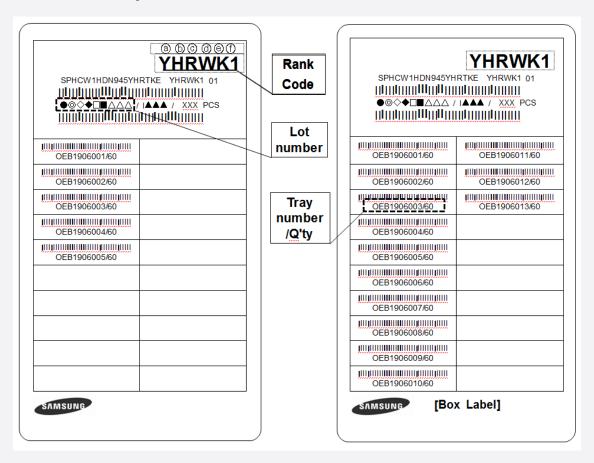


6. Label Structure

a) Label Structure

Aluminum Bag & Inner Box

Outer Box



Note: Denoted rank code and product code above is only an example (see description on page 5)

Rank Code:

(refer to page 6-7)

© d: Chromaticity bin (refer to page 8-9)

(ef): Luminous Flux bin (refer to page 6-7)



b) Lot Number

The lot number is composed of the following characters:

● ◎ ◇ ◆ □ ■ △ △ △ / 1 ▲ ▲ ▲ / xxx PCS

• : Production site (S: Giheung, Korea, G: Tianjin, China)

© : L (LED)

: Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

• Year (Y: 2014, Z: 2015, A: 2016, ...)

☐ : Month (1~9, A, B, C)

■ : Day (1~9, A, B~V)

 $\triangle \triangle \triangle$: Product serial number (001 ~ 009)

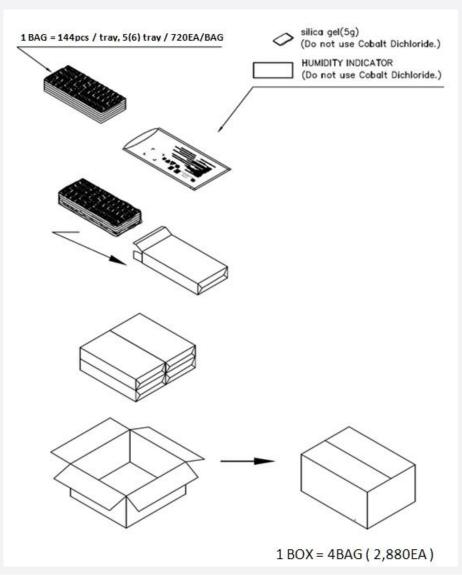
▲ ▲ : Tray number (001 ~ 999)



7. Packing Structure

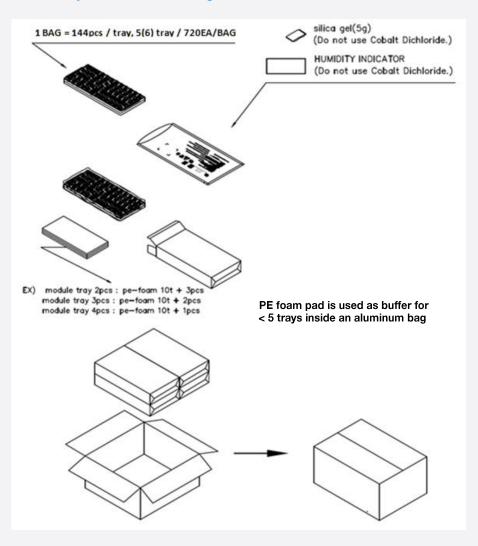
Dealting material	Max. quantity	Dimension (mm)			
Packing material	in pcs of COB	Length	Width	Height	Tolerance
Tray	144	322.6	135.9	11	0.25
Aluminum Bag	720 (5 trays)	450	230	_	10
PE Foam Pad	-	280	130	10	2
Inner Box	720 (1 aluminum bag)	338	143	55	2
Outer Box	2880 (4 inner boxes)	346	303	120	5
Pallet	161,280 (56 outer boxes)	1000	1000	970	10

a) Packing Structure for 5 trays inside Aluminum Bag

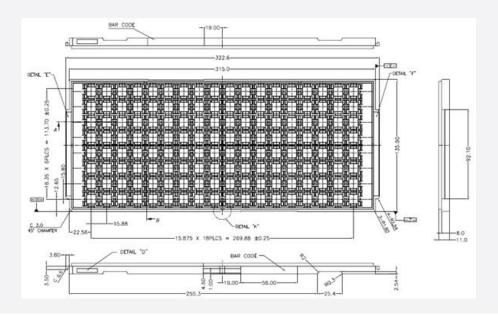




b) Packing Structure for <5 trays inside Aluminum Bag

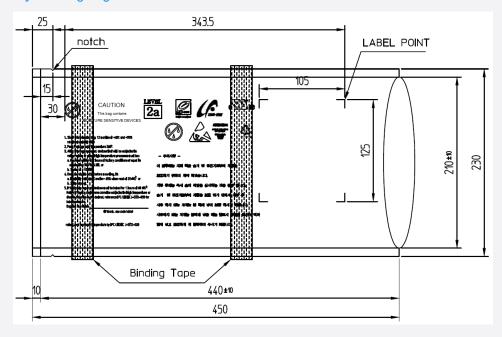


c) Tray



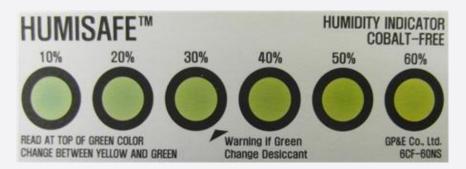


d) Aluminum Vinyl Packing Bag



e) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Packing Bag

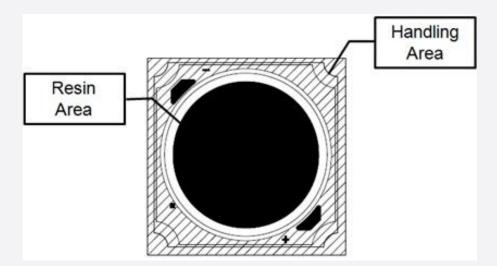






8. Precautions in Handling & Use

- 1) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 - b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 6) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 9) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.





Legal and additional information.

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